NSN 5961-01-469-1385

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-469-1385 **Inclosure Material:** Glass and metal **Overall Length:** 0.375 inches **Terminal Length:** 0.200 inches **Overall Diameter:** 0.200 inches **End Application:** 6625-15-064-3505 test set electronics systems x925-501 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 13.0 regulator voltage **Current Rating Per Characteristic:** 19.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Same as 1n4743a but with different quality level **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.